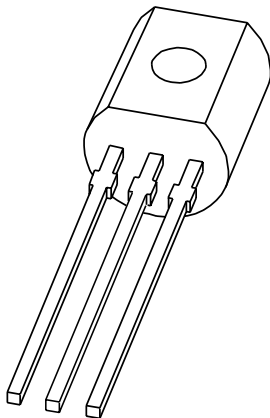


# DATA SHEET



## **PH2222A** NPN switching transistor

Product specification  
Supersedes data of 1997 Sep 04

1999 Apr 27

NPN switching transistor

PH2222A

FEATURES

- High current (max. 600 mA)
- Low voltage (max. 40 V).

APPLICATIONS

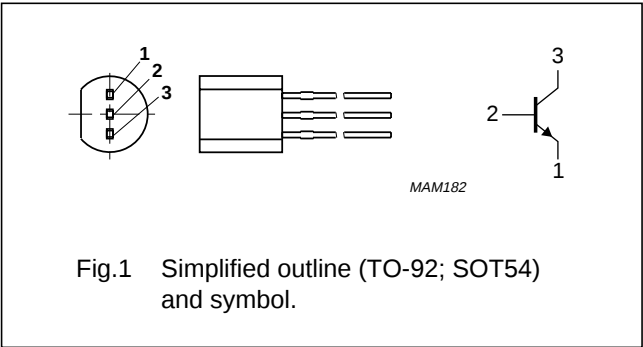
- Switching and linear amplification.

DESCRIPTION

NPN switching transistor in a TO-92; SOT54 plastic package. PNP complement: PH2907A.

PINNING

| PIN | DESCRIPTION |
|-----|-------------|
| 1   | emitter     |
| 2   | base        |
| 3   | collector   |



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

| SYMBOL    | PARAMETER                     | CONDITIONS                                | MIN. | MAX. | UNIT               |
|-----------|-------------------------------|-------------------------------------------|------|------|--------------------|
| $V_{CBO}$ | collector-base voltage        | open emitter                              | –    | 75   | V                  |
| $V_{CEO}$ | collector-emitter voltage     | open base                                 | –    | 40   | V                  |
| $V_{EBO}$ | emitter-base voltage          | open collector                            | –    | 6    | V                  |
| $I_C$     | collector current (DC)        |                                           | –    | 600  | mA                 |
| $I_{CM}$  | peak collector current        |                                           | –    | 800  | mA                 |
| $I_{BM}$  | peak base current             |                                           | –    | 200  | mA                 |
| $P_{tot}$ | total power dissipation       | $T_{amb} \leq 25\text{ }^{\circ}\text{C}$ | –    | 500  | mW                 |
| $T_{stg}$ | storage temperature           |                                           | –65  | +150 | $^{\circ}\text{C}$ |
| $T_j$     | junction temperature          |                                           | –    | 150  | $^{\circ}\text{C}$ |
| $T_{amb}$ | operating ambient temperature |                                           | –65  | +150 | $^{\circ}\text{C}$ |

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## THERMAL CHARACTERISTICS

| SYMBOL        | PARAMETER                                   | CONDITIONS | VALUE | UNIT |
|---------------|---------------------------------------------|------------|-------|------|
| $R_{th\ j-a}$ | thermal resistance from junction to ambient | note 1     | 250   | K/W  |

## Note

1. Transistor mounted on an FR4 printed-circuit board.

## CHARACTERISTICS

$T_j = 25\ ^\circ\text{C}$  unless otherwise specified.

| SYMBOL      | PARAMETER                            | CONDITIONS                                                                                                 | MIN. | MAX. | UNIT          |
|-------------|--------------------------------------|------------------------------------------------------------------------------------------------------------|------|------|---------------|
| $I_{CBO}$   | collector cut-off current            | $I_E = 0; V_{CB} = 60\text{ V}$                                                                            | –    | 10   | nA            |
|             |                                      | $I_E = 0; V_{CB} = 60\text{ V}; T_{amb} = 150\ ^\circ\text{C}$                                             | –    | 10   | $\mu\text{A}$ |
| $I_{EBO}$   | emitter cut-off current              | $I_C = 0; V_{EB} = 3\text{ V}$                                                                             | –    | 10   | nA            |
| $h_{FE}$    | DC current gain                      | $I_C = 0.1\text{ mA}; V_{CE} = 10\text{ V}$                                                                | 35   | –    |               |
|             |                                      | $I_C = 1\text{ mA}; V_{CE} = 10\text{ V}$                                                                  | 50   | –    |               |
|             |                                      | $I_C = 10\text{ mA}; V_{CE} = 10\text{ V}$                                                                 | 75   | –    |               |
|             |                                      | $I_C = 10\text{ mA}; V_{CE} = 10\text{ V}; T_{amb} = -55\ ^\circ\text{C}$                                  | 35   | –    |               |
|             |                                      | $I_C = 150\text{ mA}; V_{CE} = 1\text{ V}; \text{note 1}$                                                  | 50   | –    |               |
|             |                                      | $I_C = 150\text{ mA}; V_{CE} = 10\text{ V}; \text{note 1}$                                                 | 100  | 300  |               |
|             |                                      | $I_C = 500\text{ mA}; V_{CE} = 10\text{ V}; \text{note 1}$                                                 | 40   | –    |               |
| $V_{CEsat}$ | collector-emitter saturation voltage | $I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{note 1}$                                                   | –    | 300  | mV            |
|             |                                      | $I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{note 1}$                                                   | –    | 1    | V             |
| $V_{BEsat}$ | base-emitter saturation voltage      | $I_C = 150\text{ mA}; I_B = 15\text{ mA}; \text{note 1}$                                                   | 0.6  | 1.2  | V             |
|             |                                      | $I_C = 500\text{ mA}; I_B = 50\text{ mA}; \text{note 1}$                                                   | –    | 2    | V             |
| $C_c$       | collector capacitance                | $I_E = I_C = 0; V_{CB} = 10\text{ V}; f = 1\text{ MHz}$                                                    | –    | 8    | pF            |
| $C_e$       | emitter capacitance                  | $I_C = I_E = 0; V_{EB} = 500\text{ mV}; f = 1\text{ MHz}$                                                  | –    | 25   | pF            |
| $f_T$       | transition frequency                 | $I_C = 20\text{ mA}; V_{CE} = 20\text{ V}; f = 100\text{ MHz}$                                             | 300  | –    | MHz           |
| $F$         | noise figure                         | $I_C = 200\ \mu\text{A}; V_{CE} = 5\text{ V}; R_S = 2\text{ k}\Omega; f = 1\text{ kHz}; B = 200\text{ Hz}$ | –    | 4    | db            |

**Switching times (between 10% and 90% levels); see Fig.2**

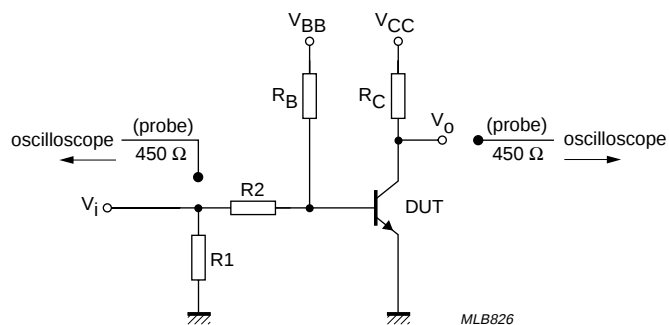
|           |               |                                                                             |   |     |    |
|-----------|---------------|-----------------------------------------------------------------------------|---|-----|----|
| $t_{on}$  | turn-on time  | $I_{Con} = 150\text{ mA}; I_{Bon} = 15\text{ mA}; I_{Boff} = -15\text{ mA}$ | – | 35  | ns |
| $t_d$     | delay time    |                                                                             | – | 15  | ns |
| $t_r$     | rise time     |                                                                             | – | 20  | ns |
| $t_{off}$ | turn-off time |                                                                             | – | 250 | ns |
| $t_s$     | storage time  |                                                                             | – | 200 | ns |
| $t_f$     | fall time     |                                                                             | – | 60  | ns |

## Note

1. Pulse test:  $t_p \leq 300\ \mu\text{s}; \delta \leq 0.02$ .

## NPN switching transistor

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$V_i = 9.5 \text{ V}$ ;  $T = 500 \mu\text{s}$ ;  $t_p = 10 \mu\text{s}$ ;  $t_r = t_f \leq 3 \text{ ns}$ .  
 $R_1 = 68 \Omega$ ;  $R_2 = 325 \Omega$ ;  $R_B = 325 \Omega$ ;  $R_C = 160 \Omega$ .  
 $V_{BB} = -3.5 \text{ V}$ ;  $V_{CC} = 29.5 \text{ V}$ .  
Oscilloscope: input impedance  $Z_i = 50 \Omega$ .

Fig.2 Test circuit for switching times.

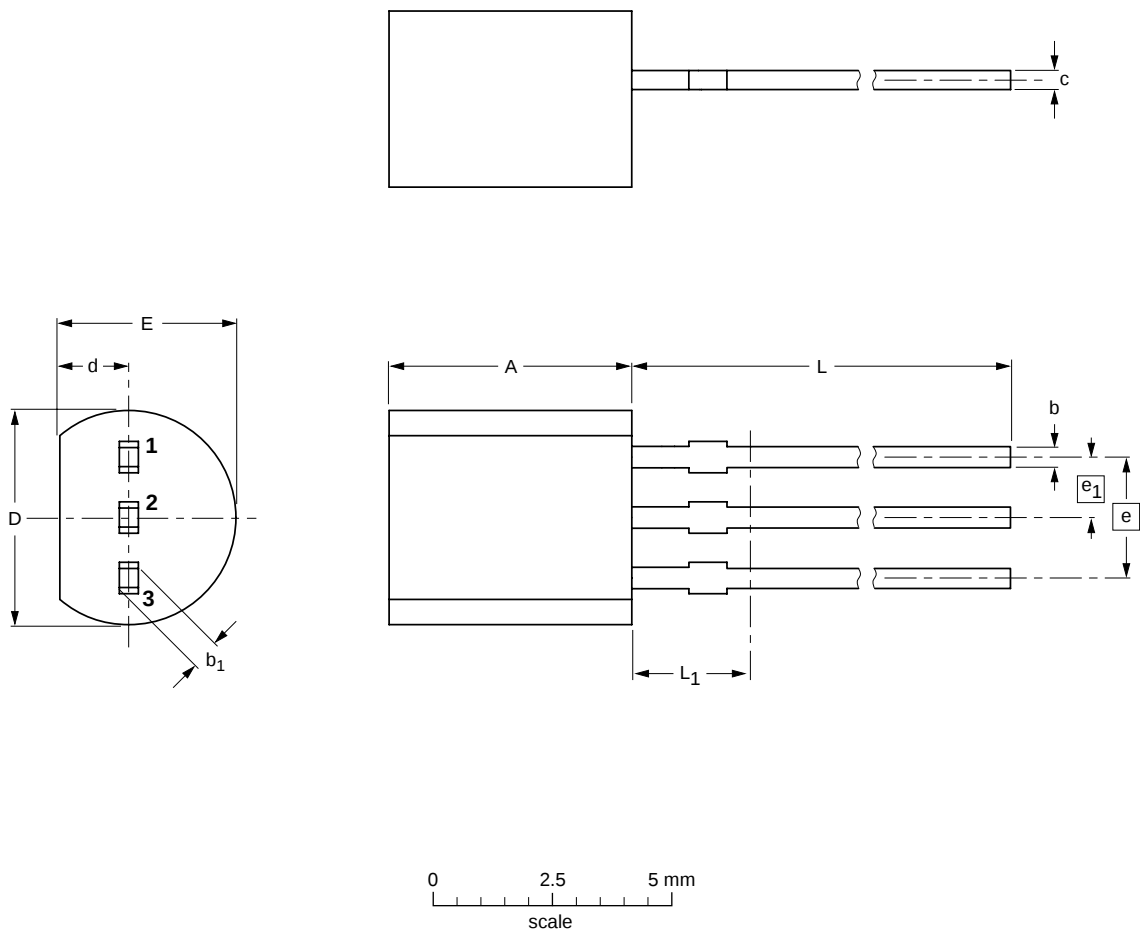
NPN switching transistor

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PACKAGE OUTLINE

Plastic single-ended leaded (through hole) package; 3 leads

SOT54



DIMENSIONS (mm are the original dimensions)

| UNIT | A          | b            | b <sub>1</sub> | c            | D          | d          | E          | e    | e <sub>1</sub> | L            | L <sub>1</sub> <sup>(1)</sup> |
|------|------------|--------------|----------------|--------------|------------|------------|------------|------|----------------|--------------|-------------------------------|
| mm   | 5.2<br>5.0 | 0.48<br>0.40 | 0.66<br>0.56   | 0.45<br>0.40 | 4.8<br>4.4 | 1.7<br>1.4 | 4.2<br>3.6 | 2.54 | 1.27           | 14.5<br>12.7 | 2.5                           |

Note

1. Terminal dimensions within this zone are uncontrolled to allow for flow of plastic and terminal irregularities.

| OUTLINE<br>VERSION | REFERENCES |       |       |  | EUROPEAN<br>PROJECTION | ISSUE DATE |
|--------------------|------------|-------|-------|--|------------------------|------------|
|                    | IEC        | JEDEC | EIAJ  |  |                        |            |
| SOT54              |            | TO-92 | SC-43 |  |                        | 97-02-28   |

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NPN switching transistor

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**DEFINITIONS**

| <b>Data sheet status</b>                                                                                                                                                                                                                                                                                                                                                                                                                                  |                                                                                       |
|-----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|---------------------------------------------------------------------------------------|
| Objective specification                                                                                                                                                                                                                                                                                                                                                                                                                                   | This data sheet contains target or goal specifications for product development.       |
| Preliminary specification                                                                                                                                                                                                                                                                                                                                                                                                                                 | This data sheet contains preliminary data; supplementary data may be published later. |
| Product specification                                                                                                                                                                                                                                                                                                                                                                                                                                     | This data sheet contains final product specifications.                                |
| <b>Limiting values</b>                                                                                                                                                                                                                                                                                                                                                                                                                                    |                                                                                       |
| Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability. |                                                                                       |
| <b>Application information</b>                                                                                                                                                                                                                                                                                                                                                                                                                            |                                                                                       |
| Where application information is given, it is advisory and does not form part of the specification.                                                                                                                                                                                                                                                                                                                                                       |                                                                                       |

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Printed in The Netherlands

115002/00/04/pp8

Date of release: 1999 Apr 27

Document order number: 9397 750 05428

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